

# ON Semiconductor

## Is Now

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# BAT54CXV3

## Dual Series Schottky Barrier Diodes

These Schottky barrier diodes are designed for high speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand held and portable applications where space is limited.

### Features

- Extremely Fast Switching Speed
- Low Forward Voltage – 0.35 V (Typ) @  $I_F = 10 \text{ mA}$ dc
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

### MAXIMUM RATINGS ( $T_J = 125^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Reverse Voltage	$V_R$	30	V
Forward Power Dissipation @ $T_A = 25^\circ\text{C}$ Derate above $25^\circ\text{C}$	$P_F$	240 1.9	mW mW/ $^\circ\text{C}$
Forward Current (DC)	$I_F$	200 Max	mA
Non-Repetitive Peak Forward Current, $t_p < 10 \text{ msec}$	$I_{FSM}$	600	mA
Repetitive Peak Forward Current Pulse Wave = 1 sec, Duty Cycle = 66%	$I_{FRM}$	300	mA
Junction Temperature	$T_J$	-55 to 125	$^\circ\text{C}$
Storage Temperature Range	$T_{stg}$	-55 to +150	$^\circ\text{C}$
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	525	$^\circ\text{C}/\text{W}$

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-4 board with minimum mounting pad.



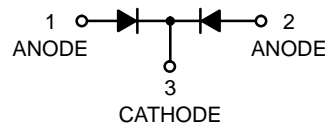
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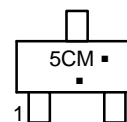
### 30 VOLT DUAL COMMON CATHODE SCHOTTKY BARRIER DIODES



SC-89  
CASE 463C  
STYLE 3



### MARKING DIAGRAM



5C = Device Code  
M = Date Code  
▪ = Pb-Free Package

(Note: Microdot may be in either location)

### ORDERING INFORMATION

Device	Package	Shipping†
BAT54CXV3T1G	SC-89 (Pb-Free)	3000 / Tape & Reel

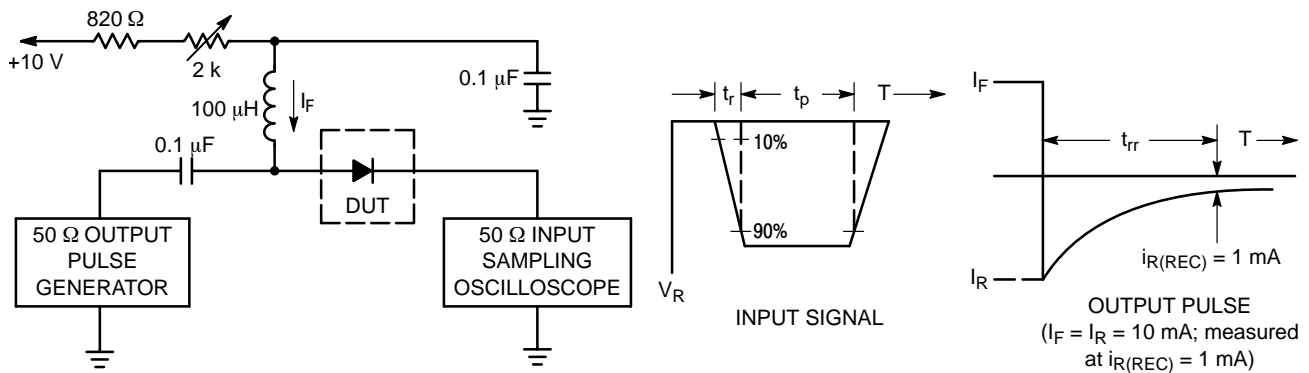
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# BAT54CXV3

## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted) (EACH DIODE)

Characteristic	Symbol	Min	Typ	Max	Unit
Reverse Breakdown Voltage ( $I_R = 10\ \mu\text{A}$ )	$V_{(BR)R}$	30	–	–	V
Total Capacitance ( $V_R = 1.0\ \text{V}$ , $f = 1.0\ \text{MHz}$ )	$C_T$	–	7.6	10	pF
Reverse Leakage ( $V_R = 25\ \text{V}$ )	$I_R$	–	0.5	2.0	$\mu\text{A}_{dc}$
Forward Voltage ( $I_F = 0.1\ \text{mA}$ ) ( $I_F = 1.0\ \text{mA}$ ) ( $I_F = 10\ \text{mA}$ ) ( $I_F = 30\ \text{mA}$ ) ( $I_F = 100\ \text{mA}$ )	$V_F$	– – – – –	0.22 0.29 0.35 0.41 0.52	0.24 0.32 0.40 0.50 0.80	V
Reverse Recovery Time ( $I_F = I_R = 10\ \text{mA}$ , $I_{R(REC)} = 1.0\ \text{mA}$ , Figure 1)	$t_{rr}$	–	–	5.0	ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



- Notes: 1. A 2.0 k $\Omega$  variable resistor adjusted for a Forward Current ( $I_F$ ) of 10 mA.  
 2. Input pulse is adjusted so  $I_{R(\text{peak})}$  is equal to 10 mA.  
 3.  $t_p \gg t_{rr}$

Figure 1. Recovery Time Equivalent Test Circuit

# BAT54CXV3

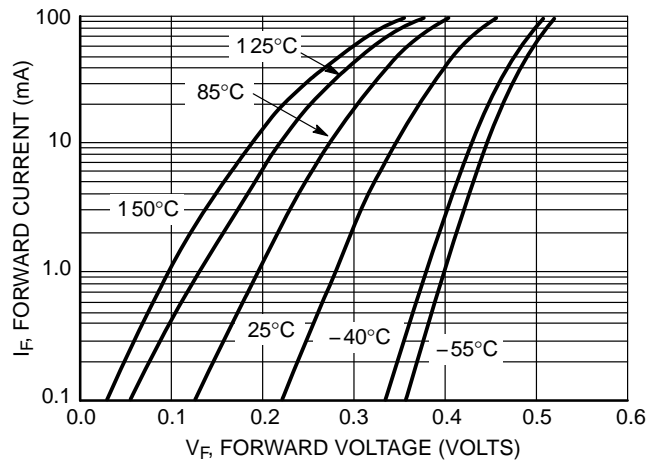


Figure 2. Forward Voltage

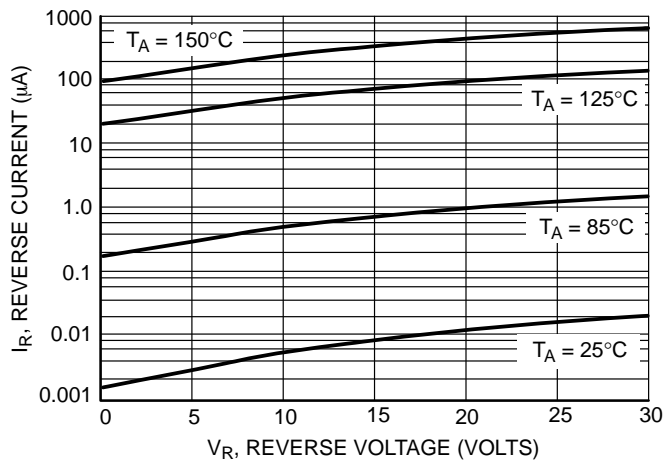


Figure 3. Leakage Current

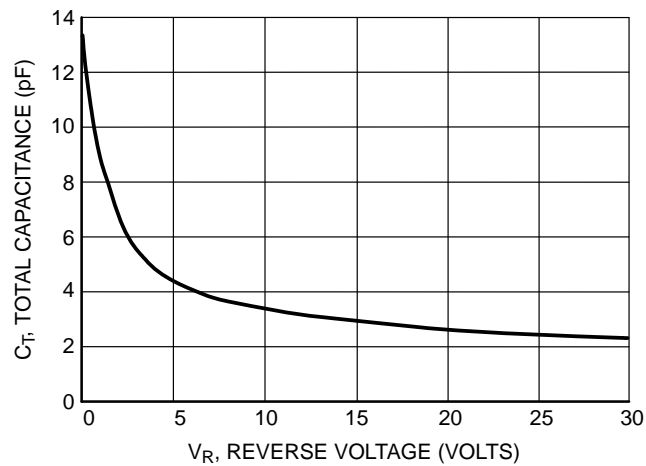


Figure 4. Total Capacitance

# MECHANICAL CASE OUTLINE

## PACKAGE DIMENSIONS

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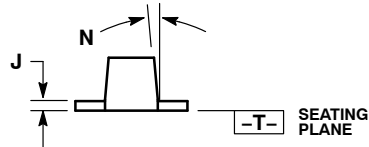
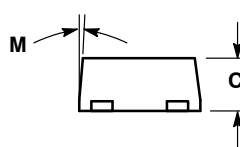
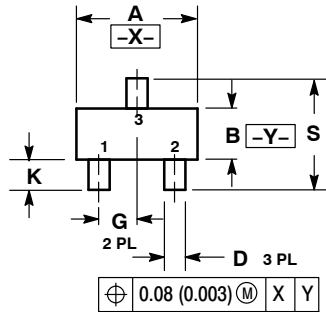


### SC-89, 3 LEAD CASE 463C-03 ISSUE C

DATE 31 JUL 2003



SCALE 4:1

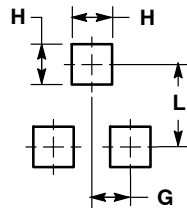


STYLE 1:  
PIN 1. BASE  
2. EMITTER  
3. COLLECTOR

STYLE 2:  
PIN 1. ANODE  
2. N/C  
3. CATHOD-

STYLE 3:  
PIN 1. ANODE  
2. ANODE  
3. CATHODE

STYLE 4:  
PIN 1. CATHODE  
2. CATHODE  
3. ANODE



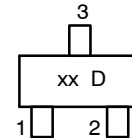
RECOMMENDED PATTERN OF SOLDER PADS

NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.
- 463C-01 OBSOLETE, NEW STANDARD 463C-02.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.50	1.60	1.70	0.059	0.063	0.067
B	0.75	0.85	0.95	0.030	0.034	0.040
C	0.60	0.70	0.80	0.024	0.028	0.031
D	0.23	0.28	0.33	0.009	0.011	0.013
G	0.50 BSC			0.020 BSC		
H	0.53 REF			0.021 REF		
J	0.10	0.15	0.20	0.004	0.006	0.008
K	0.30	0.40	0.50	0.012	0.016	0.020
L	1.10 REF			0.043 REF		
M	---	---	10	---	---	10
N	---	---	10	---	---	10
S	1.50	1.60	1.70	0.059	0.063	0.067

### GENERIC MARKING DIAGRAM\*



xx = Specific Device Code  
D = Date Code

\*This information is generic. Please refer to device data sheet for actual part marking.

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